TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

TLP141G

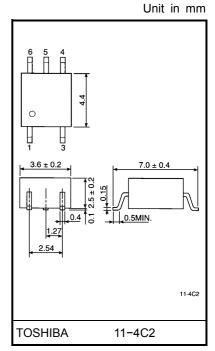
Programmable Controllers
AC-Output Module
Solid State Relay

The TOSHIBA mini flat coupler TLP141G is a small outline coupler, suitable for surface mount assembly.

The TLP141G consists of a photo thyristor, optically coupled to a gallium arsenide infrared emitting diode.

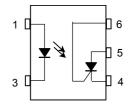
Peak off-state voltage: 400 V (min.)
Trigger LED current: 10 mA (max.)
On-state current: 150 mA (max.)

Isolation voltage: 2500 Vrms (min.)
UL recognized: UL1577, file no. E67349



Weight: 0.09 g

Pin Connections



- 1 : Anode
- 3 : Cathode
- 4 : Cathode
- 5 : Anode.
- 6 : Gate

Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit	
	Forward current	IF	50	mA	
	Forward current derating (Ta ≥ 53°C)	ΔI _F /°C	-0.7	mA / °C	
LED	Peak forward current (100 µs pulse, 100 pps)	I _{FP}	1	Α	
	Reverse voltage	V _R	5	V	
	Junction temperature	Tj	125	°C	
	Peak forward voltage($R_{GK} = 27k\Omega$)	V_{DRM}	400	V	
Detector	Peak reverse voltage(R _{GK} = 27kΩ)	V_{DRM}	400	V	
	On–state current	I _{T(RMS)}	150	mA	
	On–state current derating (Ta ≥ 25°C)	ΔI _T / °C	-2.0	mA / °C	
	Peak one cycle surge current	I _{TSM}	2	Α	
	Peak reverse gate voltage	V_{GM}	5	V	
	Junction temperature	Tj	100	°C	
Storage	e temperature range	T _{stg}	-55~125	°C	
Operat	ing temperature range	T _{opr}	-55~100	°C	
Lead s	oldering temperature (10 s)	T _{sol}	260	°C	
Isolatio	n voltage (AC, 1 min., RH ≤ 60%) (Note 1)	BV_S	2500	Vrms	

(Note 1) Device considered a two terminal device: pins 1 and 3 shorted together and pins 4, 5 and 6 shorted together.

2

Recommended Operating Conditions

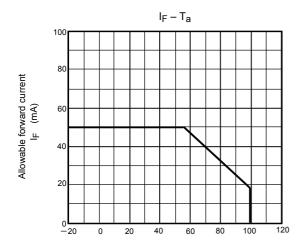
Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V_{AC}	_	_	120	Vac
Forward current	I _F	15	20	25	mA
Operating temperature	T _{opr}	-25	_	85	°C
Gate to cathode resistance	R _{GK}	_	27	33	kΩ
Gate to cathode capacitance	C _{GK}	-	0.01	0.1	μF

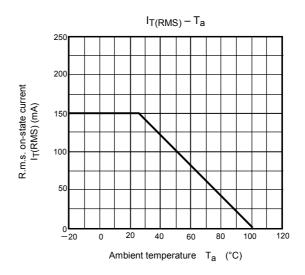
Individual Electrical Characteristics (Ta = 25°C)

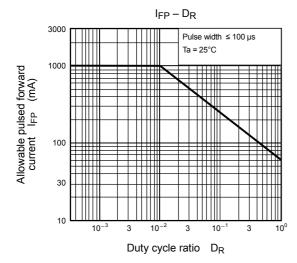
Characteristic		Symbol	Test Condition		Min.	Тур.	Max.	Unit
LED	Forward voltage	V _F	I _F = 10 mA		1.0	1.15	1.3	V
	Reverse current	I _R	V _R = 5 V		_	_	10	μΑ
	Capacitance	C _T	V = 0, f = 1 MHz		_	30	_	pF
Detector	Off-state current	I _{DRM}	V _{AK} = 400 V R _{GK} = 27 kΩ	Ta = 25°C	_	10	5000	nA
				Ta = 100°C	_	1	100	μA
	Reverse current	I _{RRM}	V _{KA} = 70 mA	Ta = 25°C	_	10	5000	nA
			R_{GK} = 27 k Ω	Ta = 100°C	_	1	100	μΑ
	On-state voltage	V _{TM}	I _{TM} = 100 mA		_	0.9	1.3	V
	Holding current	lΗ	R _{GK} = 27 kΩ		_	0.2	1	mA
	Off-state dv / dt	dv/dt	V _{AK} = 280 V, R _{GK} = 27 kΩ		5	10	_	V / µs
	Capacitance C _j V	C.	V = 0, f = 1 MHz	Anode to gate	_	20	_	ηE
			Gate to cathode	_	350	_	pF	

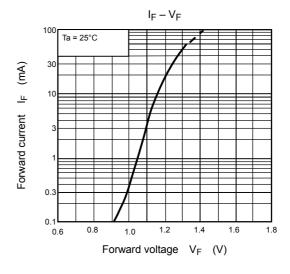
Coupled Characteristics (Ta = 25°C)

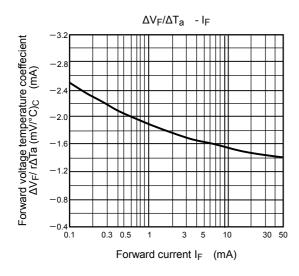
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current	I _{FT}	$V_{AK} = 6 \text{ V}, R_{GK} = 27 \text{k}\Omega$	_	4	10	mA
Turn-on time	t _{on}	I_F = 50mA, R_{GK} = 27kΩ	_	10	_	μs
Coupled dv / dt	dv/dt	$V_S = 500 \text{ V}, R_{GK} = 27 \text{k}\Omega$	500	_	_	V / µs
Capacitance (input to output)	C _S	V _S = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴	_	Ω
		AC, 1 minute	2500	_	_	Vrms
Isolation voltage		AC, 1 second, in oil	_	5000	_	VIIIIS
		DC, 1 minute, in oil	_	5000	_	Vdc

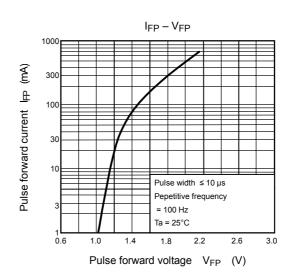


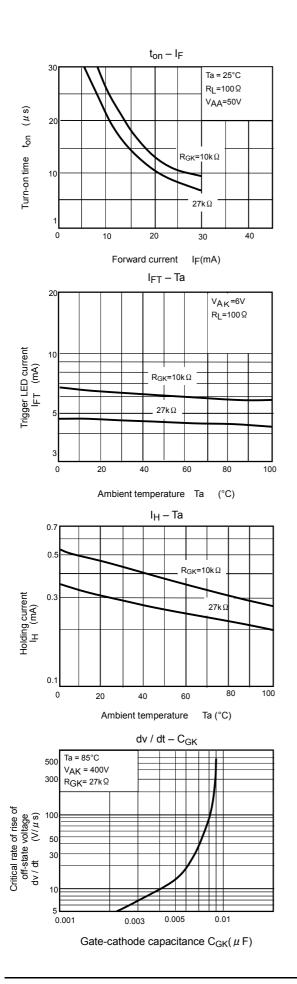


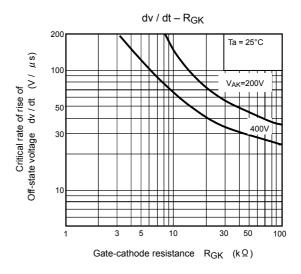


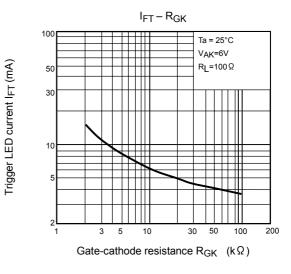


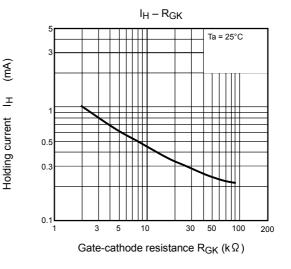












5 2002-09-25

RESTRICTIONS ON PRODUCT USE

000707EBC

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes
 are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the
 products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with
 domestic garbage.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No
 responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other
 rights of the third parties which may result from its use. No license is granted by implication or otherwise under
 any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.